

Vishay Siliconix

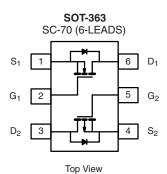
Complementary 2.5 V (G-S) MOSFET

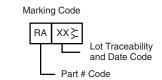
PRODUCT SUMMARY						
	V _{DS} (V)	R_{DS(on)} (Ω)	I _D (A)			
N-Channel	20	0.385 at V _{GS} = 4.5 V	± 0.70			
		0.630 at V _{GS} = 2.5 V	± 0.54			
P-Channel	- 20	0.995 at V _{GS} = - 4.5 V	± 0.44			
		1.800 at V _{GS} = - 2.5 V	± 0.32			

FEATURES

- Halogen-free According to IEC 61249-2-21 Definition
- TrenchFET[®] Power MOSFET
- Compliant to RoHS Directive 2002/95/EC •







Ordering Information: Si1553DL-T1-E3 (Lead (Pb)-free)

Si1553DL-T1-GE3 (Lead (Pb)-free and Halogen-free)

Parameter		Symbol	N-Channel		P-Channel		
			5 s	Steady State	5 s	Steady State	Unit
Drain-Source Voltage		V _{DS}	20		- 20		v
Gate-Source Voltage	e-Source Voltage		± 12			v	
	T _A = 25 °C	- I _D	± 0.70	± 0.66	± 0.44	± 0.41	
Continuous Drain Current $(T_J = 150 \ ^{\circ}C)^a$	T _A = 85 °C		± 0.50	± 0.48	± 0.31	± 0.30	
Pulsed Drain Current		I _{DM}	± 1				A
Continuous Source Current (Diode Conduction) ^a		۱ _S	0.25	0.23	- 0.25	- 0.23	
	T _A = 25 °C	Б	0.30	0.27	0.30	0.27	w
Maximum Power Dissipation ^a	T _A = 85 °C	P _D	0.16	0.14	0.16	0.14	vv
Operating Junction and Storage Temperature Range		T _J , T _{stg}	- 55 to 150				°C

THERMAL RESISTANCE RATINGS							
Parameter		Symbol	Typical	Maximum	Unit		
Movimum lunction to Ambienta	$t \le 5 s$	R _{thJA}	360	415			
Maximum Junction-to-Ambient ^a	Steady State		400	460	°C/W		
Maximum Junction-to-Foot (Drain)	Steady State	R _{thJF}	300	350			

Notes:

a. Surface mounted on 1" x 1" FR4 board.

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Parameter	Symbol	Test Conditions		Min.	Тур.	Max.	Unit	
Static	·	·						
Gate Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}, I_D = 250 \ \mu A$ N-C		0.6			v	
		$V_{DS} = V_{GS}$, $I_D = -250 \ \mu A$	P-Ch	- 0.6			v	
Gate-Body Leakage	I _{GSS}	V_{DS} = 0 V, V_{GS} = ± 12 V	N-Ch			± 100	nA	
			P-Ch			± 100		
Zero Gate Voltage Drain Current	I _{DSS}	$V_{DS} = 16 V, V_{GS} = 0 V$	N-Ch			1	μA	
		V _{DS} = - 16 V, V _{GS} = 0 V	P-Ch			- 1		
		$V_{DS} = 16 \text{ V}, V_{GS} = 0 \text{ V}, T_{J} = 85 \text{ °C}$ N-Ch				5	P** `	
		V_{DS} = - 16 V, V_{GS} = 0 V, T_{J} = 85 °C	P-Ch			- 5		
On-State Drain Current ^a	I _{D(on)}	$V_{DS} \geq 5$ V, V_{GS} = 4.5 V	N-Ch	1			А	
	·D(01)	V_{DS} \leq - 5 V, V_{GS} = - 4.5 V	P-Ch	P-Ch - 1			~	
Drain-Source On-State Resistance ^a	R _{DS(on)}	$V_{GS} = 4.5 \text{ V}, \text{ I}_{D} = 0.66 \text{ A}$	N-Ch		0.320	0.385		
		V _{GS} = - 4.5 V, I _D = - 0.41 A	P-Ch		0.850	0.995	Ω	
		$V_{GS} = 2.5 \text{ V}, \text{ I}_{D} = 0.40 \text{ A}$	N-Ch		0.560	0.630	52	
		V_{GS} = - 2.5 V, I _D = - 0.25 A	P-Ch		1.400	1.800		
Forward Transconductance ^a	9 _{fs}	V _{DS} = 10 V, I _D = 0.66 A	N-Ch		1.5		s	
		V _{DS} = - 10 V, I _D = - 0.41 A	P-Ch		0.8		3	
Diada Farmand Valta and	V _{SD}	$I_{S} = 0.23 \text{ A}, V_{GS} = 0 \text{ V}$	N-Ch		0.8	1.2	v	
Diode Forward Voltage ^a		I _S = - 0.23 A, V _{GS} = 0 V	P-Ch		- 0.8	- 1.2	v	
Dynamic ^b								
Total Gate Charge	Q _q		N-Ch		0.8	1.2		
	۵g	N-Channel V _{DS} = 10 V, V _{GS} = 4.5 V, I _D = 0.66 A	P-Ch		1.2	1.8		
Gate-Source Charge	Q _{qs}	$v_{\rm DS} = 10^{-1}$, $v_{\rm GS} = 4.0^{-1}$, $D = 0.00^{-1}$	N-Ch		0.06		nC	
5	93	P-Channel	P-Ch N-Ch		0.45		-	
Gate-Drain Charge	Q _{gd}	$US = 10^{\circ}$, $UGS = 10^{\circ}$, $UD = 0.11$			0.30 0.25			
			P-Ch N-Ch		10	20		
Turn-On Delay Time	t _{d(on)}	N-Channel	P-Ch		7.5	15		
Rise Time	t _r	V_{DD} = 10 V, R_L = 20 Ω	N-Ch		16	30		
		$\text{I}_\text{D} \cong$ 0.5 A, V_GEN = 4.5 V, R_g = 6 Ω	P-Ch		20	40		
Turn-Off Delay Time	t _{d(off)}	P-Channel	N-Ch		10	20	1	
		$V_{DD} = -10 \text{ V}, \text{ R}_{L} = 20 \Omega$	P-Ch		8.5	17	ns	
Fall Time	t _f	$\text{I}_{\text{D}}\cong$ - 0.5 A, V_{GEN} = - 4.5 V, R_{g} = 6 Ω	N-Ch		10	20		
			P-Ch		12	24		
Source-Drain Reverse Recovery Time	t _{rr}	I _F = 0.23 A, dl/dt = 100 A/μs N-Ch			20	40		
		I _F = - 0.23 A, dl/dt = 100 A/μs	P-Ch		25	40		

Notes:

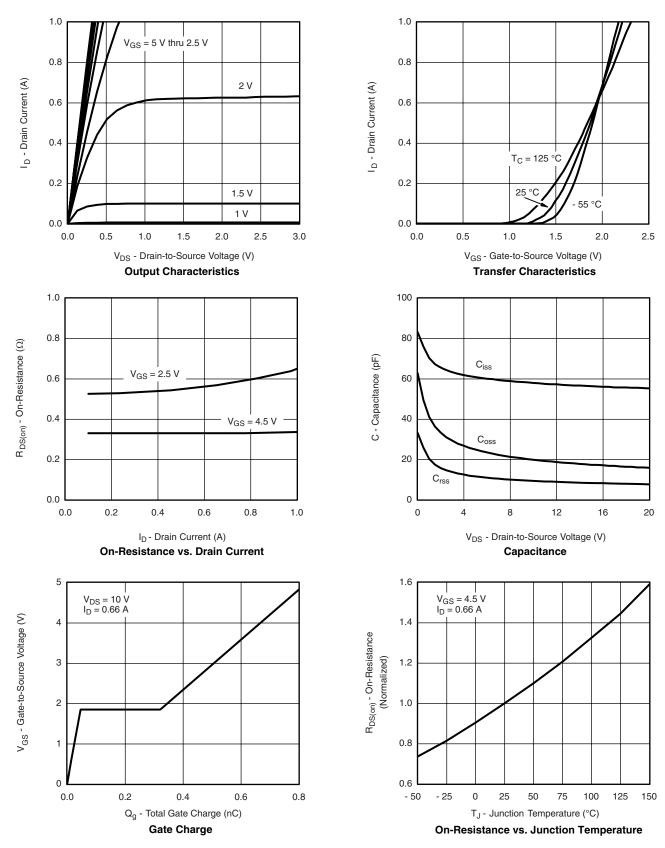
a. Pulse test; pulse width \leq 300 µs, duty cycle \leq 2 %.

b. Guaranteed by design, not subject to production testing.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



N-CHANNEL TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted

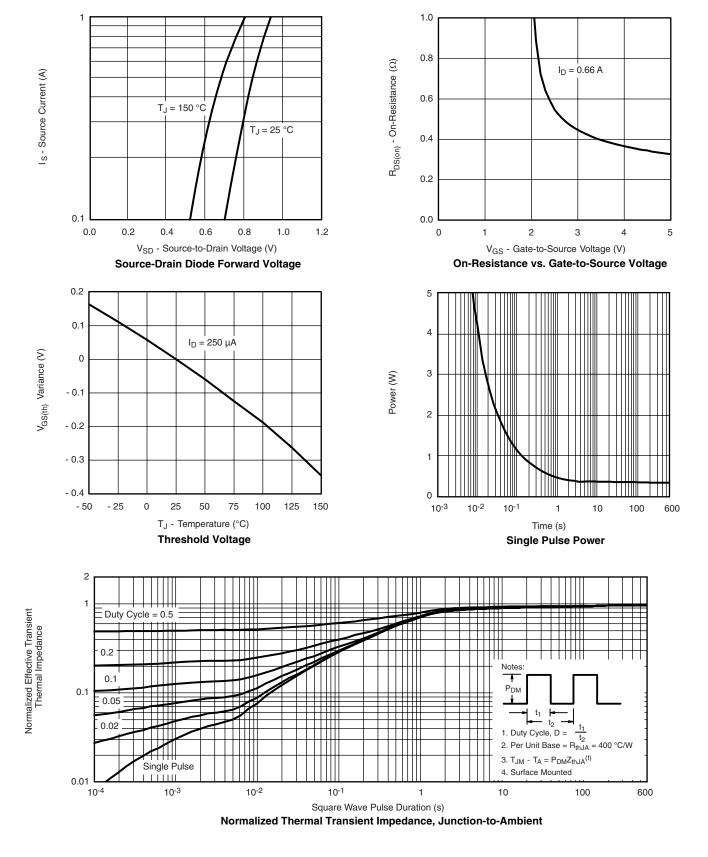


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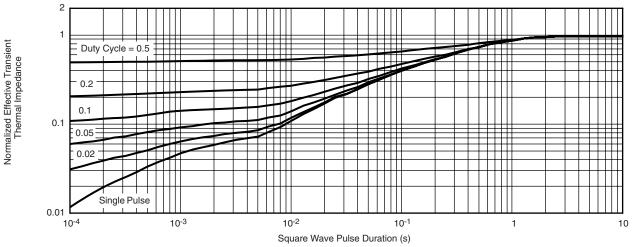






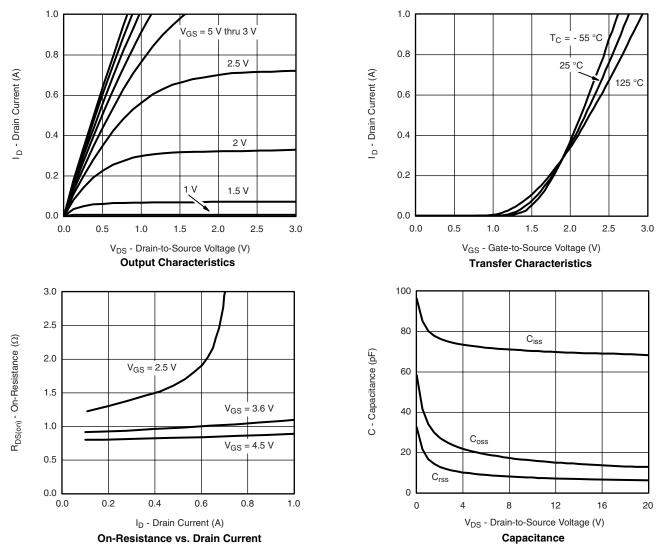
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N-CHANNEL TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



Normalized Thermal Transient Impedance, Junction-to-Foot





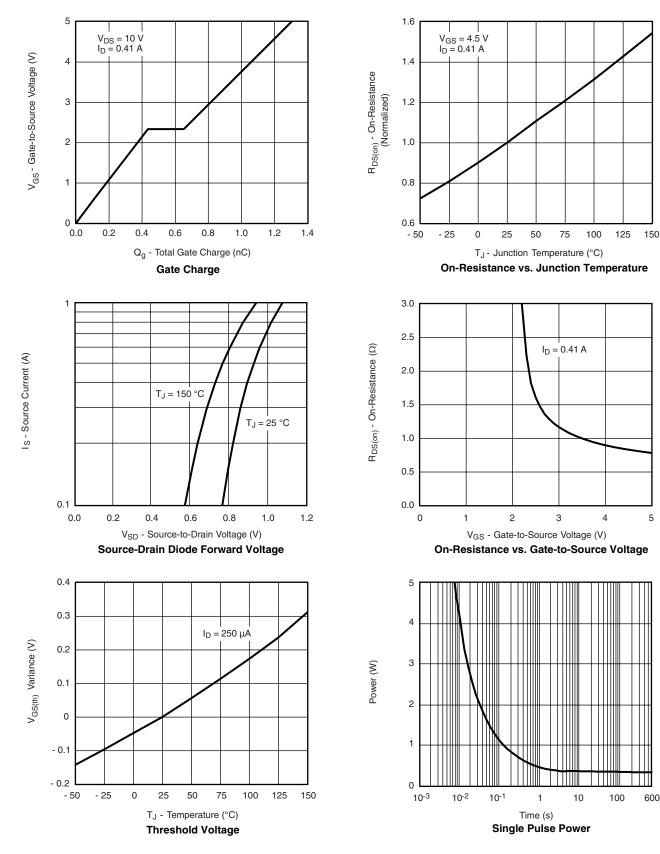
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P-CHANNEL TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



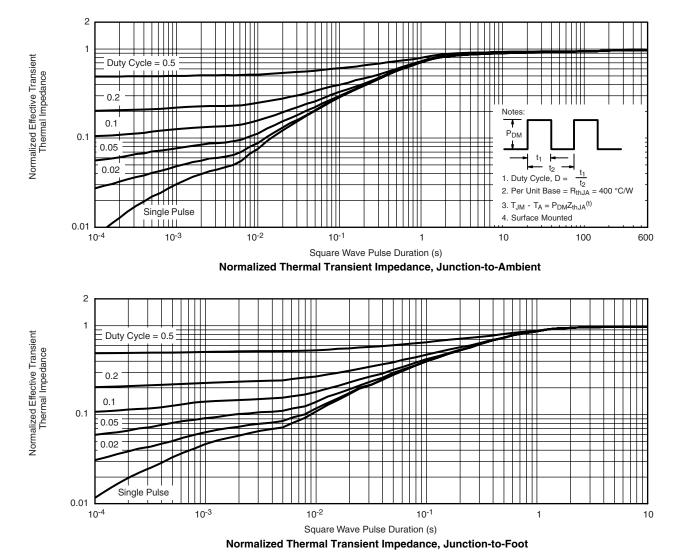
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P-CHANNEL TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted

Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see www.vishay.com/ppg?71078.



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